

## PESDHC2FD4V8UHF

### **Uni-directional 4.8V High Capacitance ESD Protector**

#### **Description**

The PESDHC2FD4V8UHF ESD protector is designed to replace multilayer varistors (MLVs) in portable applications such as cell phones, notebook computers, and PDA's. They feature large cross-sectional area junctions for conducting high transient currents, offer desirable electrical characteristics for board level protection, such as fast response time, lower operating voltage, lower clamping voltage and no device degradation when compared to MLVs. The PESDHC2FD4V8UHF protects sensitive semiconductor components from damage or upset due to electrostatic discharge (ESD) and other voltage induced transient events.

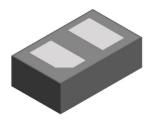
The PESDHC2FD4V8UHF is available in a DFN1006-2L package with working voltages of 4.8 volt. It gives designer the flexibility to protect one unidirectional line in applications where arrays are not practical. Additionally, it may be "sprinkled" around the board in applications where board space is at a premium.

#### Feature

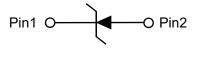
- 1000W peak pulse power per line (t<sub>P</sub> = 8/20µs)
- DFN1006-2L package
- Response time is typically < 1 ns</p>
- Unidirectional configurations
- Low clamping voltage
- RoHS compliant
- Transient protection for data lines to IEC 61000-4-2(ESD) ±30kV(air), ± 30kV(contact); IEC 61000-4-5 (Lightning) 100A (8/20us)

#### **Applications**

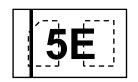
- Cell phone handsets and accessories
- Personal digital assistants (PDA's)
- Notebooks, desktops, and servers
- Portable instrumentation
- Cordless phones
- Digital cameras
- Peripherals



DFN1006-2L(Bottom View)



**Circuit Diagram** 



Marking (Top View)

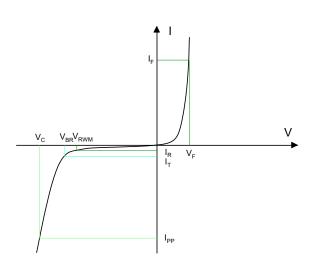
#### **Mechanical Characteristics**

- Mounting position: Any
- Qualified max reflow temperature:260°C
- Device meets MSL 1 requirements
- DFN1006-2L without plating

# PESDHC2FD4V8UHF

#### **Electronics Parameter**

Symbol	Parameter		
V <sub>RWM</sub>	Peak Reverse Working Voltage		
I <sub>R</sub>	Reverse Leakage Current @ V <sub>RWM</sub>		
V <sub>BR</sub> Breakdown Voltage @ I <sub>T</sub>			
Ι <sub>Τ</sub>	Test Current		
I <sub>PP</sub>	Maximum Reverse Peak Pulse Current		
V <sub>c</sub>	Clamping Voltage @ I <sub>PP</sub>		
P <sub>PP</sub>	Peak Pulse Power		
CJ	Junction Capacitance		
I <sub>F</sub>	Forward Current		
V <sub>F</sub>	V <sub>F</sub> Forward Voltage @ I <sub>F</sub>		



### Electrical characteristics per line@25°C (unless otherwise specified)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Units
Peak Reverse Working Voltage	V <sub>RWM</sub>	-	-	-	4.8	V
Breakdown Voltage	V <sub>BR</sub>	I <sub>t</sub> = 1mA	5	5.8	6.5	V
Reverse Leakage Current	I <sub>R</sub>	V <sub>RWM</sub> = 4.8V	-	-	1	μA
Clamping Voltage <sup>1)</sup>	V <sub>c</sub>	TLP = 16A, t <sub>p</sub> = 100ns	-	7	-	V
Dynamic resistance <sup>1)</sup>	R <sub>DYN</sub>	-	-	0.04	-	Ω
Clamping Voltage <sup>2)</sup>	V <sub>c</sub>	I <sub>PP</sub> = 40A,t <sub>P</sub> = 8/20µs	-	7	9	V
		I <sub>PP</sub> = 100A,t <sub>P</sub> = 8/20μs	-	10	12	V
Junction Capacitance	CJ	V <sub>R</sub> = 0V,f = 1MHz	-	230	260	pF

Notes:

1.TLP parameter:  $Z_0=50\Omega$ ,  $t_p=100$ ns,  $t_r=2$ ns, averaging window from 60ns to 80ns.  $R_{DYN}$  is calculated from 4A to 16A. 2.Non-repetitive current pulse, according to IEC61000-4-5.

### Absolute maximum rating@25°C

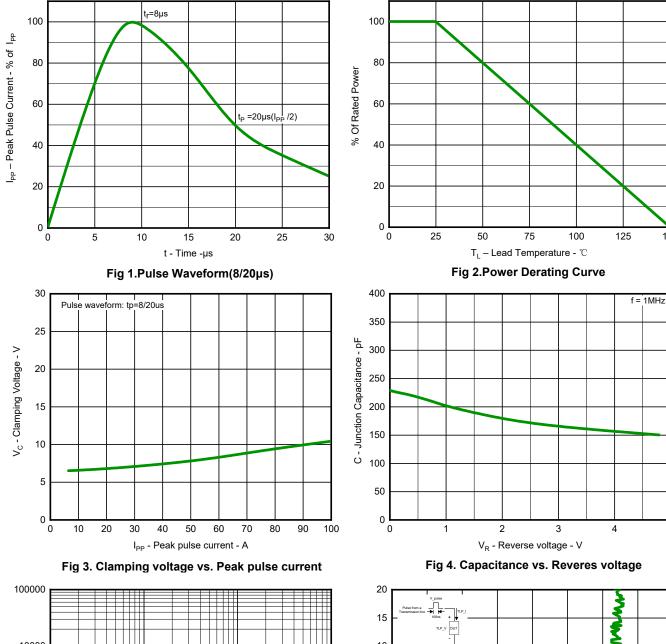
Rating	Symbol	Value	Units
Peak Pulse Power(t <sub>P</sub> = 8/20µs)	P <sub>PP</sub>	1000	W
Peak Pulse Current ( t <sub>P</sub> = 8/20µs )	I <sub>PP</sub>	100	А
Lead Soldering Temperature	TL	260 (10 sec)	°C
Junction and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-55~+150	°C
ESD Protection-Contact Discharge	V <sub>ESD</sub>	±30	kV
ESD Protection-Air Discharge	V <sub>ESD</sub>	±30	kV

## PESDHC2FD4V8UHF

150

5

## Typical Characteristics



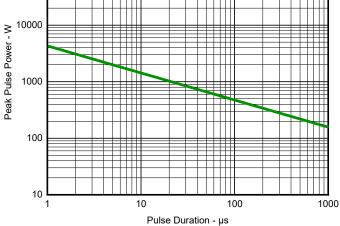


Fig 5. Non Repetitive Peak Pulse Power vs. Pulse time

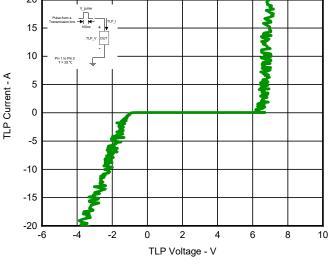


Fig 6. TLP Measurement

# PESDHC2FD4V8UHF

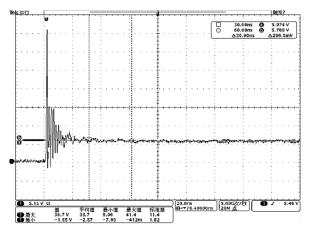


Fig 7. Clamping Voltage at IEC61000-4-2 +8kV Pulse Waveform

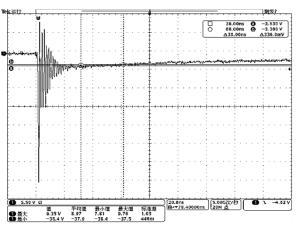
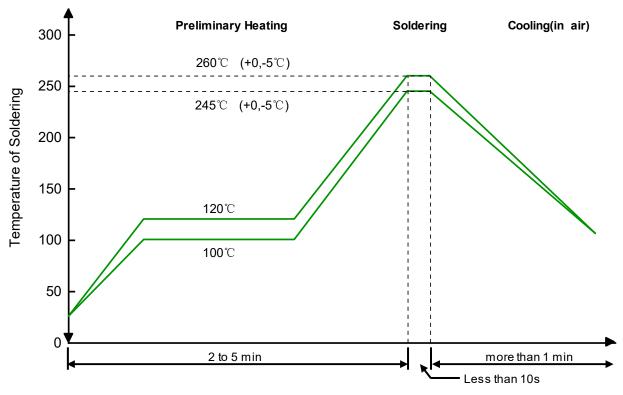


Fig 8. Clamping Voltage at IEC61000-4-2 -8kV Pulse Waveform

### **Solder Reflow Recommendation**



Remark: Pb free for 260°C; Pb for 245°C.

## PESDHC2FD4V8UHF

## **ESD** Protector

#### PCB Design

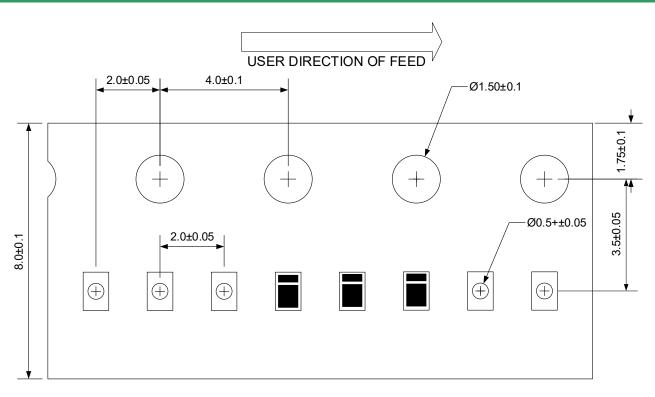
For TVS diodes a low-ohmic and low-inductive path to chassis earth is absolutely mandatory in order to achieve good ESD protection. Novices in the area of ESD protection should take following suggestions to heart:

- > Do not use stubs, but place the cathode of the TVS diode directly on the signal trace.
- > Do not make false economies and save copper for the ground connection.
- > Place via holes to ground as close as possible to the anode of the TVS diode.
- ➢ Use as many via holes as possible for the ground connection.
- > Keep the length of via holes in mind! The longer the more inductance they will have.

#### **Ordering information**

Device Package		Reel	Shipping	
PESDHC2FD4V8UHF	DFN1006-2L (Pb-Free)	7"	10000 / Tape & Reel	

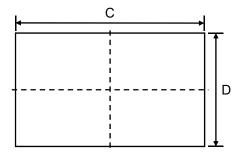
#### Load with information



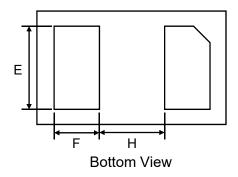
#### Unit:mm

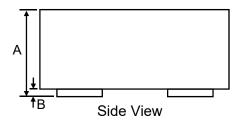
# PESDHC2FD4V8UHF

# Product dimension (DFN1006-2L)

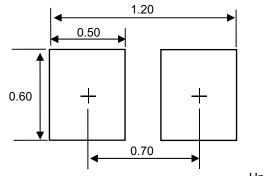








Dim	Millin	neters	Inches		
Dim	Min	Max	Min	Max	
А	0.340	0.498	0.013	0.020	
В	0.000	0.050	0.000	0.002	
С	0.950	1.080	0.037	0.043	
D	0.550	0.680	0.022	0.027	
E	0.400	0.600	0.016	0.024	
F	0.200	0.300	0.008	0.012	
Н	0.400 Тур.		0.015 Typ.		



Unit:mm



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